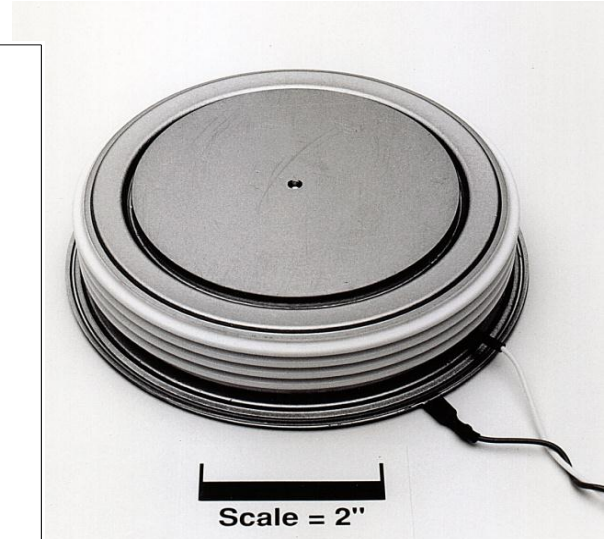
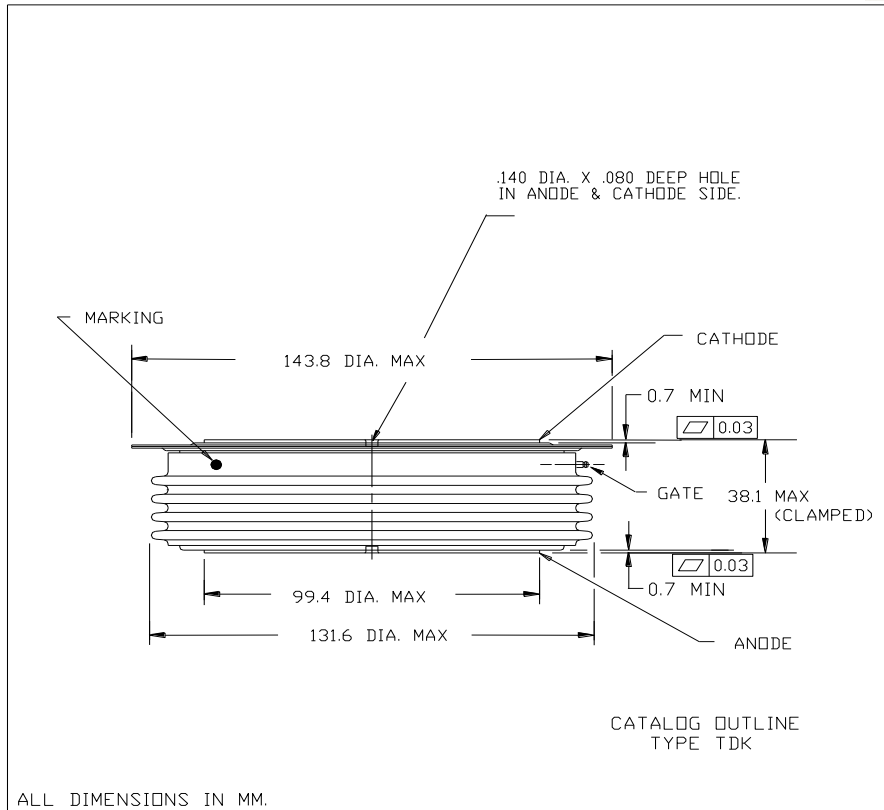




The TDK4 is a high voltage, high current disc pack SCR employing a high di/dt gate structure. This gate design allows the SCR to be reliably operated at high di/dt and dv/dt conditions in various phase control applications.

FEATURES:

- Low On-State Voltage
- High di/dt Capability
- High dv/dt Capability
- Hermetic Ceramic Package
- Excellent Surge and I^2t Ratings

APPLICATIONS:

- DC Power Supplies
- Motor Controls

ORDERING INFORMATION

Select the complete 12 digit Part Number using the table below.
EXAMPLE: TDK4363402DH is a 3600V-3400A SCR with 300ma IGT and 12 inch gate and cathode potential leads.

PART	Voltage Rating $V_{DRM}-V_{RRM}$	Voltage Code	Current Rating I_{tavg}	Current Code	Turn-Off T_q	Gate I_{GT}	Leads
TDK4	3600	36	3400	34	0	2	
	3400	34					
	3200	32			400us	300ma	12"
	3000	30			(typ.)	(max)	

Absolute Maximum Ratings[†]

Characteristic	Symbol	Rating	Units
Repetitive Peak Voltage	$V_{DRM} - V_{RRM}$	3000 - 3600	Volts
Average On-State Current, $T_C = 70^\circ\text{C}$	$I_{T(Avg.)}$	3430	A
RMS On-State Current, $T_C = 70^\circ\text{C}$	$I_{T(RMS)}$	5388	A
Average On-State Current, $T_C = 55^\circ\text{C}$	$I_{T(Avg.)}$	3745	A
RMS On-State Current, $T_C = 55^\circ\text{C}$	$I_{T(RMS)}$	5883	A
Peak One Cycle Surge Current, 60Hz, $V_R = 0V$	I_{TSM}	70,000	A
Peak One Cycle Surge Current, 50Hz, $V_R = 0V$	I_{TSM}	65,600	A
Fuse Coordination I^2t , 60Hz	I^2t	2.04E+07	A ² s
Fuse Coordination I^2t , 50Hz	I^2t	2.15E+07	A ² s
Critical Rate-of-Rise of On-State Current	di/dt	100	A/us
Repetitive from .67•VDRM			
Critical Rate-of-Rise of On-State Current	di/dt	300	A/us
Non-Repetitive from .67•VDRM			
Peak Gate Power, 100us	P_{GM}	16	Watts
Average Gate Power	$P_{G(avg)}$	5	Watts
Operating Temperature	T_j	-40 to +125	°C
Storage Temperature	$T_{Stg.}$	-40 to +150	°C
Approximate Weight		6.1	lb
		2.77	Kg
Mounting Force		18,000 - 25,000	lbs
		80 - 110	KNewtons

[†] Ratings apply for operation at rated load force.

Information presented is based upon manufacturers testing and projected capabilities. This information is subject to change without notice. The manufacturer makes no claim as to suitability for use, reliability, capability or future availability of this product.

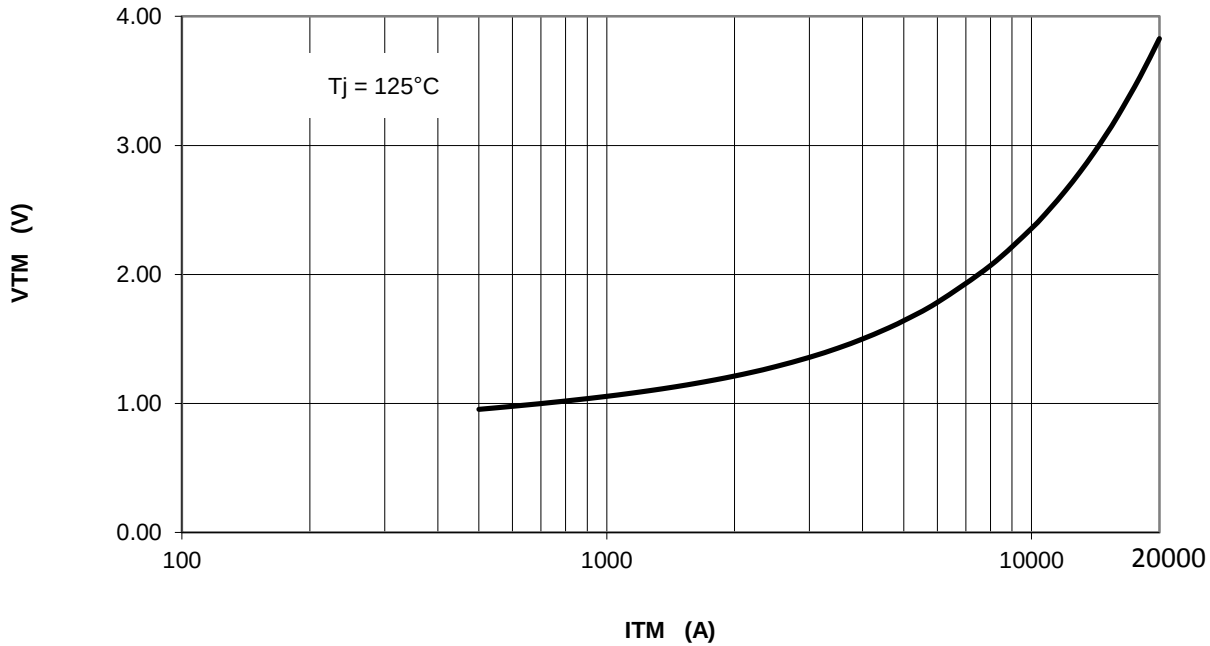
Electrical Characteristics, Tj=25°C unless otherwise specified

Characteristic	Symbol	Test Conditions	Rating			Units
			min	typ	max	
Repetitive Peak Forward Leakage Current	I_{DRM}	Tj=125°C, V_{DRM} =Rated			300	ma
Repetitive Peak Reverse Leakage Current	I_{RRM}	Tj=125°C, V_{RRM} =Rated			300	ma
Peak On-State Voltage	V_{TM}	Tj=125°C, I_{TM} =4000A			1.50	V
V_{TM} Model, Low Level	V_0	Tj=125°C			0.914	V
$V_{TM} = V_0 + r \cdot I_{TM}$	r	15% $I_{TM} - \pi \cdot I_{TM}$			0.145	mΩ
V_{TM} Model, High Level	V_0	Tj=125°C			0.802	V
$V_{TM} = V_0 + r \cdot I_{TM}$	r	$\pi \cdot I_{TM} - I_{TSM}$			0.152	mΩ
V_{TM} Model, 4-Term	A	Tj=125°C			0.285	
$V_{TM} = A + B \cdot \ln(I_{TM}) +$	B	15% $I_{TM} - I_{TSM}$			0.120	
$C \cdot (I_{TM}) + D \cdot (I_{TM})^{1/2}$	C				1.69E-04	
	D				-0.00720	
Turn-On Delay Time	t_d	$V_D = 0.5 \cdot V_{DRM}$ Gate Drive: 40V - 20Ω			3	us
Turn-Off Time (typ)	tq	Tj=125°C dv/dt = 20V/us to 80% V_{DRM}		600		us
dv/dt _(Crit)	dv/dt	Tj=125°C Exp. Waveform V_D =67% Rated	1000			V/us
Gate Trigger Current	I_{GT}	Tj=25°C $V_D = 12V$	40	100	300	ma
Gate Trigger Voltage	V_{GT}		0.8	2.0	4.0	V
Peak Reverse Gate Voltage	V_{GRM}				5	V

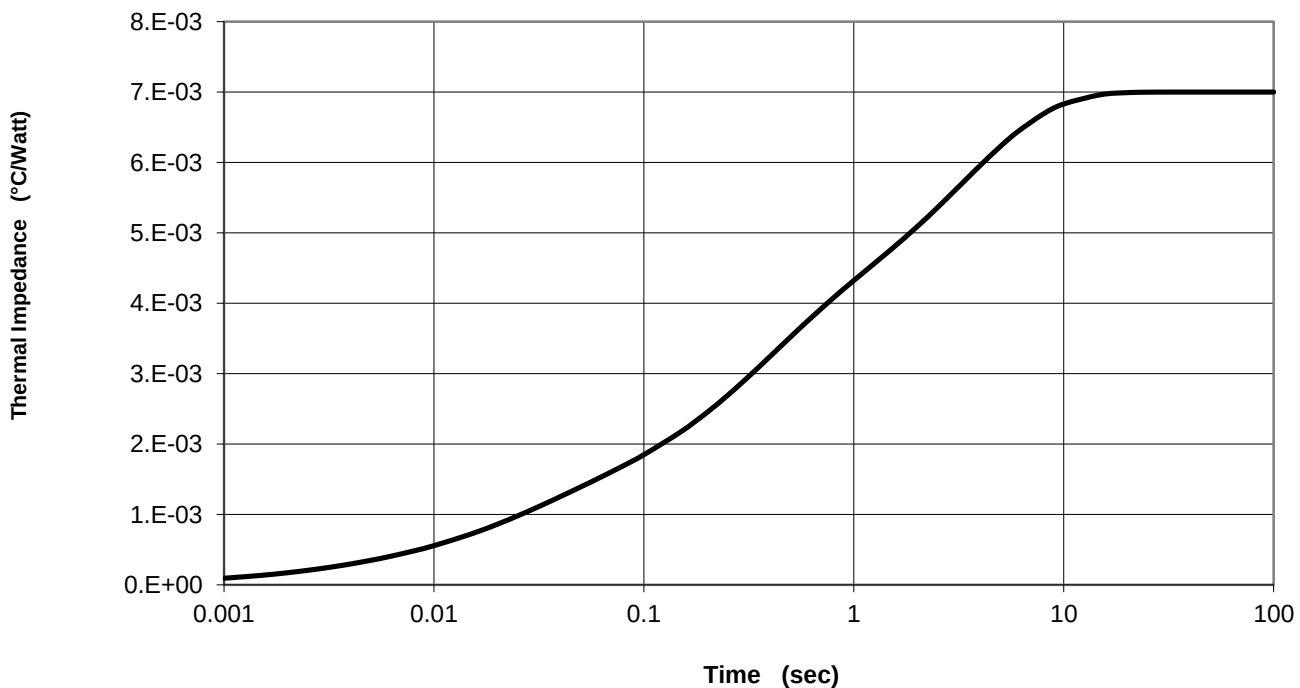
Thermal Characteristics

Characteristic	Symbol	Test Conditions	Rating			Units
			min	typ	max	
Thermal Resistance						
Junction to Case	$R\theta_{jc}$	Double side cooled		0.0055	0.007	°C/Watt
Case to Sink	$R\theta_{cs}$	Double side cooled		0.0015	0.002	°C/Watt
Thermal Impedance Model	$Z\theta_{jc}$	Double side cooled				
$Z\theta_{jc}(t) = \Sigma(A(N) \cdot (1 - \exp(-t/\text{Tau}(N))))$						
where: N = 1 2 3 4 $A(N) = 1.43E-04 \quad 9.38E-04 \quad 2.42E-03 \quad 3.50E-03$ $\text{Tau}(N) = 2.62E-03 \quad 2.31E-02 \quad 3.05E-01 \quad 3.30E+00$						

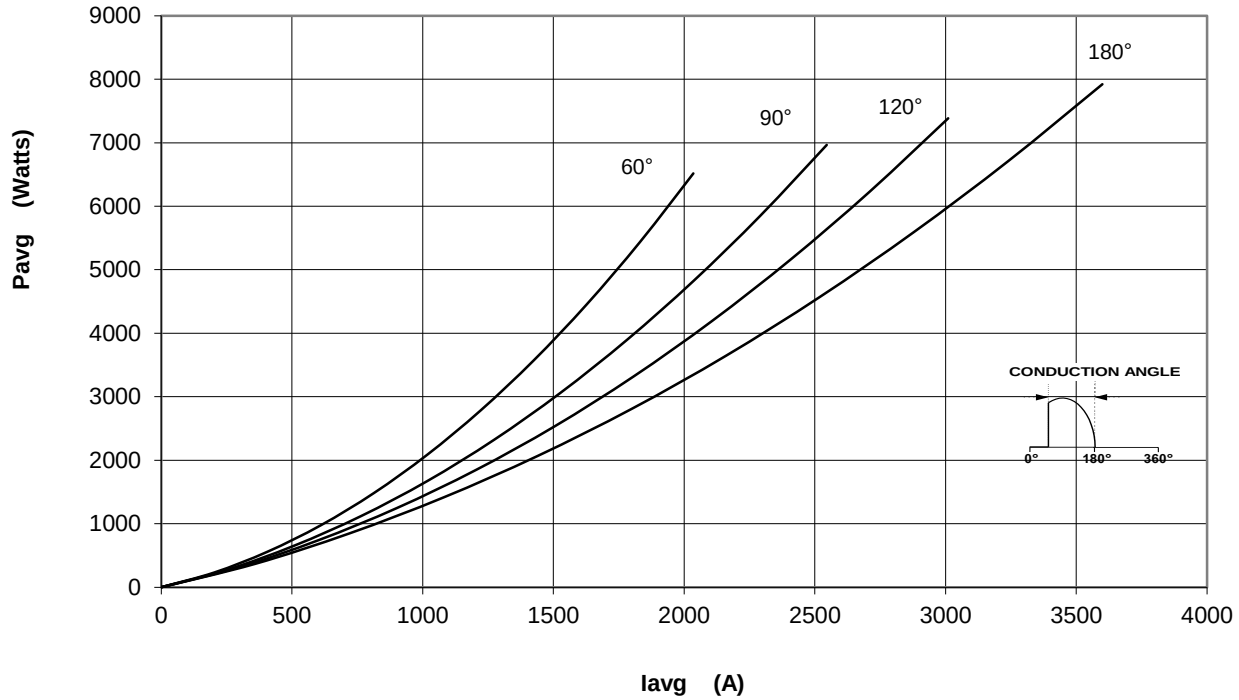
Maximum On-State Voltage Drop



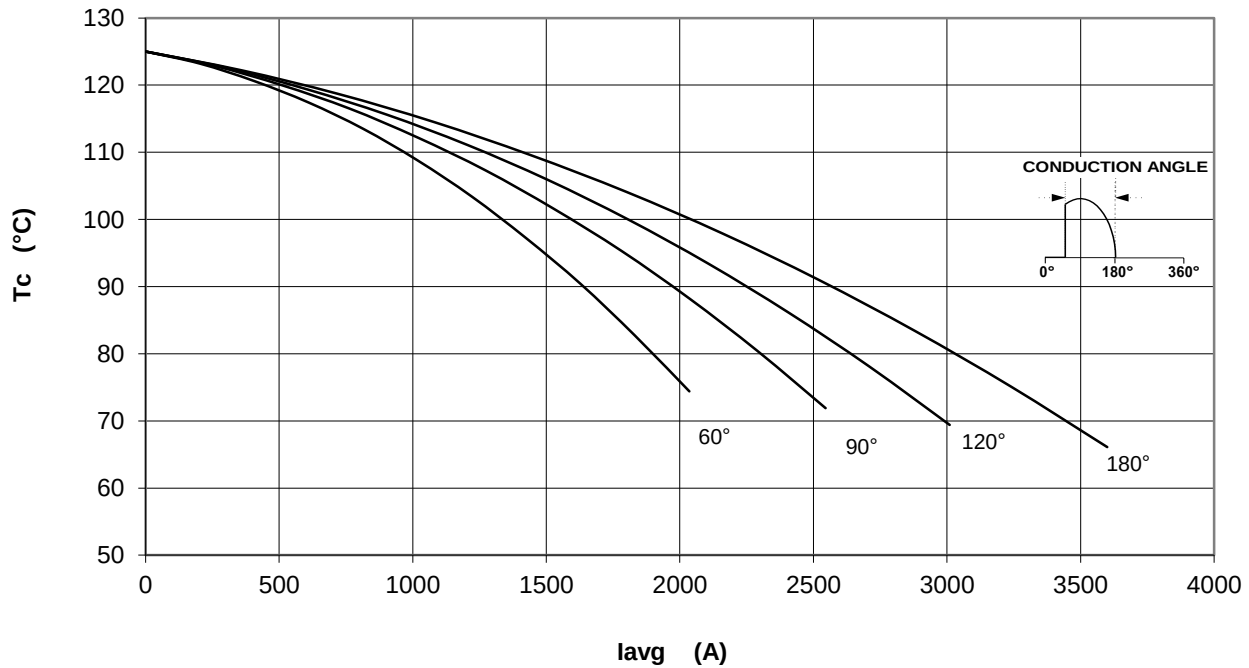
MAXIMUM TRANSIENT THERMAL IMPEDANCE



Maximum On-State Power Dissipation Sinusoidal Waveform

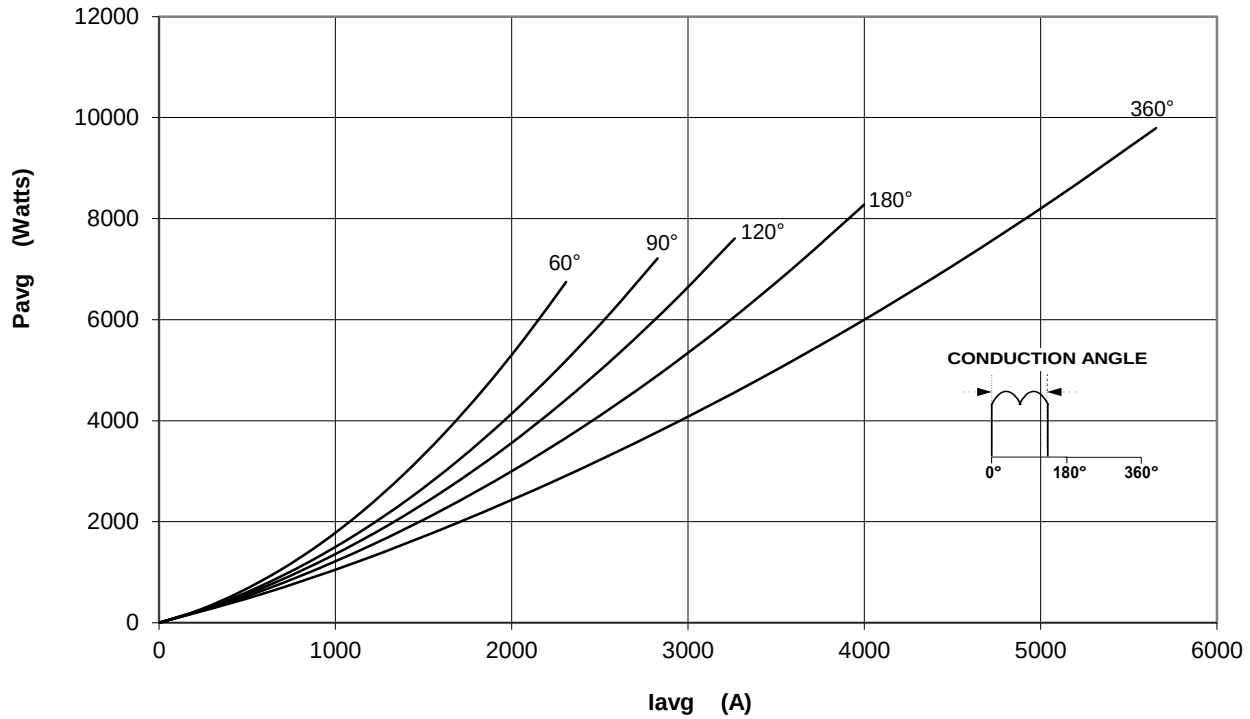


Maximum Allowable Case Temperature Sinusoidal Waveform



Maximum On-State Power Dissipation

Square Waveform



Maximum Allowable Case Temperature

Square Waveform

